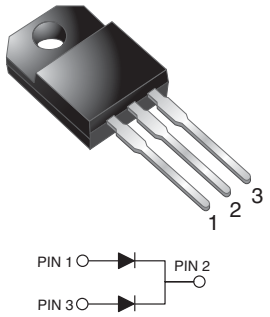
Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance

ITO-220AB



FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified
("_X" denotes revision code, e.g. A,B,...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102
E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_{RRM}	45 V
I_{FSM}	150 A
V_F	0.56 V
I_R	80 µA
T_J max.	175 °C
Package	ITO-220AB
Circuit configuration	Common cathode

MAXIMUM RATINGS (T_A = 25 °C unless otherwise noted)

PARAMETER		SYMBOL	MBRF30H45CT	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	45	V
Working peak reverse voltage		V_{RWM}	45	V
Maximum DC blocking voltage		V_{DC}	45	V
Maximum average forward rectified current (fig. 1)	total device	$I_{F(AV)}$	30	A
	per diode		15	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I_{FSM}	150	A
Peak repetitive reverse surge current per diode at t_p = 2 µs, 1 kHz		I_{RRM}	1.0	A
Peak non-repetitive reverse energy (8/20 µs waveform)		E_{RSM}	25	mJ
Non-repetitive avalanche energy per diode at 25 °C, I_{AS} = 4 A, L = 10 mH		E_{AS}	80	mJ
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 kΩ		V_C	25	kV
Voltage rate of change (rated V_R)		dV/dt	10 000	V/µs
Operating junction and storage temperature range		T_J, T_{STG}	-65 to +175	°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V_{AC}	1500	V

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ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)						
PARAMETER	**TEST CONDITIONS**		**SYMBOL**	**MBRF30H45CT**		**UNIT**
Maximum instantaneous forward voltage per diode	I_F = 15 A	T_C = 25 °C	V_F (1)	-	0.62	V
	I_F = 15 A	T_C = 125 °C		0.49	0.56	
	I_F = 30 A	T_C = 25 °C		-	0.73	
	I_F = 30 A	T_C = 125 °C		0.62	0.67	
Maximum reverse current per diode at working peak reverse voltage		T_J = 25 °C	I_R (2)	-	80	µA
		T_J = 125 °C		5.0	15	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)			
PARAMETER	**SYMBOL**	**MBRF30H45CT**	**UNIT**
Typical thermal resistance junction to case per diode	$R_{\theta JC}$	4.5	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	**PREFERRED P/N**	**UNIT WEIGHT (g)**	**PACKAGE CODE**	**BASE QUANTITY**	**DELIVERY MODE**
ITO-220AB	MBRF30H45CT-E3/45	1.99	45	50/tube	Tube
ITO-220AB	MBRF30H45CTHE3_A/P (1)	1.99	P	50/tube	Tube

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

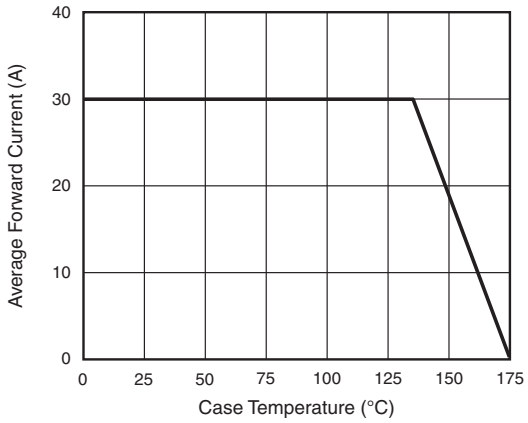


Fig. 1 - Forward Derating Curve

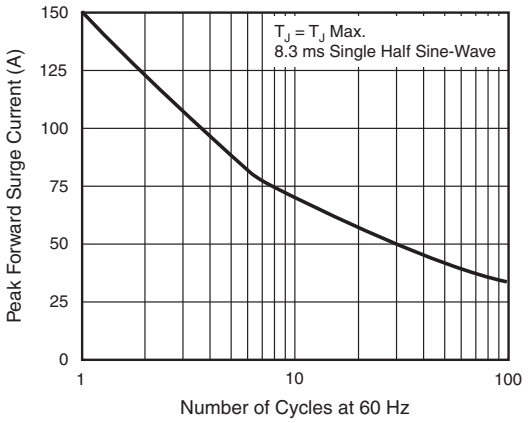


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

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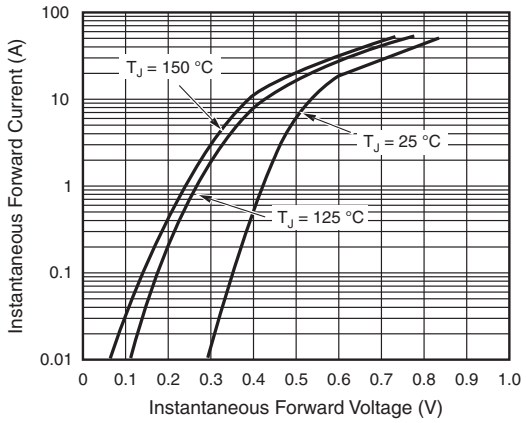


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

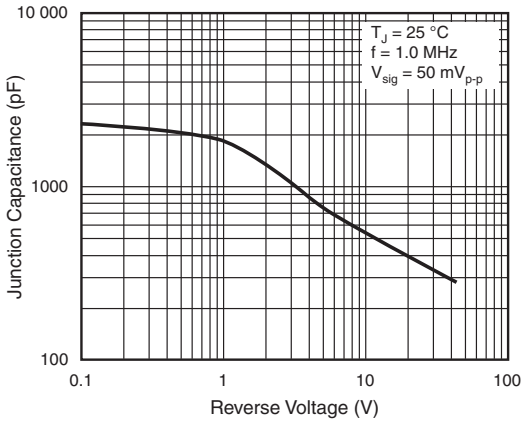


Fig. 5 - Typical Junction Capacitance Per Diode

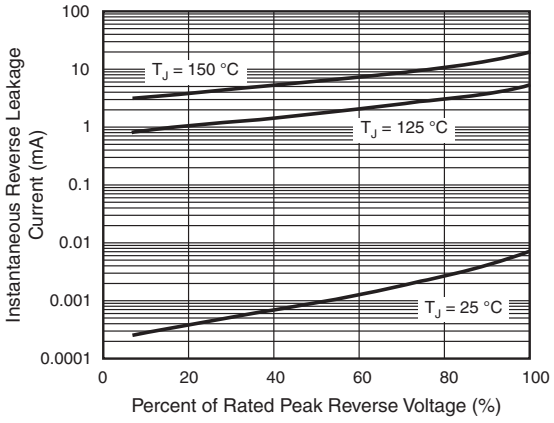


Fig. 4 - Typical Reverse Characteristics Per Diode

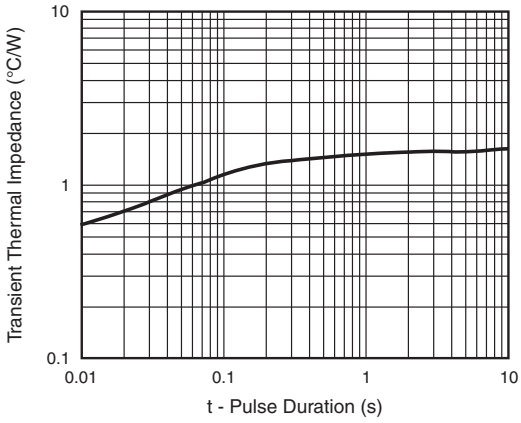
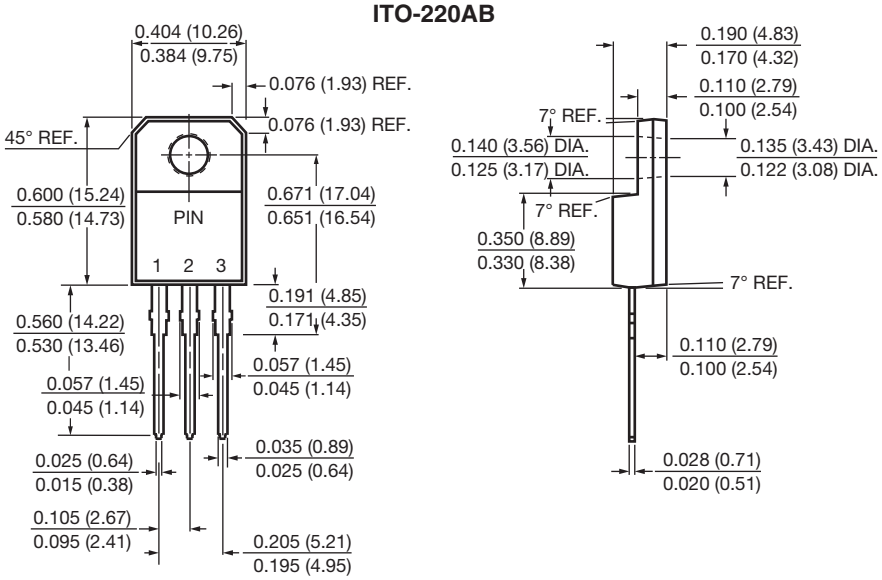


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB



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